

SEMICONDUCTOR®

# **BC182B**

- NPN General Purpose AmplifierThis device is designed for general purpose amplifier application at collector currents to 100mA.
- Sourced from process 10.



1. Collector 2. Base 3. Emitter

# Absolute Maximum Ratings $T_{C}=25^{\circ}C$ unless otherwise noted

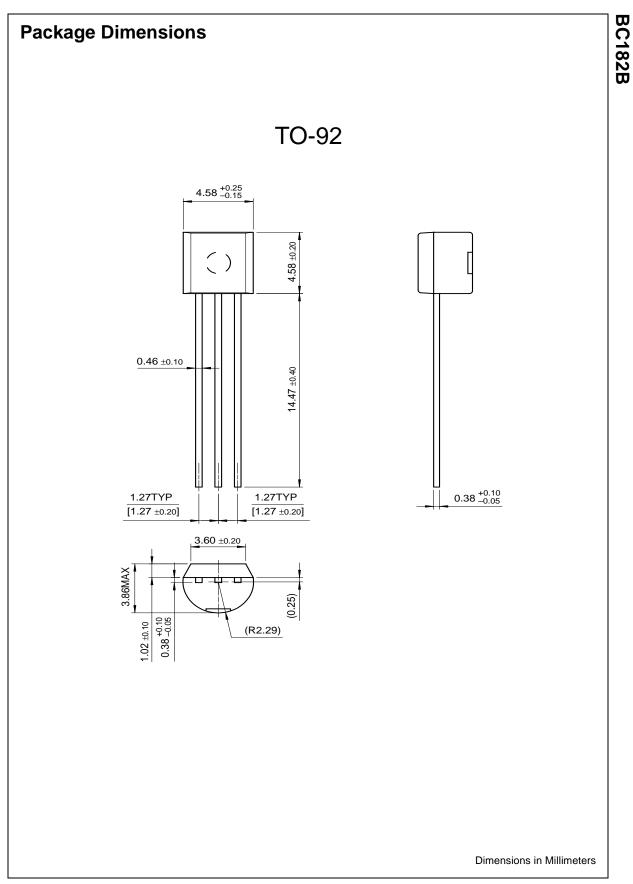
Symbol	Parameter	Value	Units	
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V	
V <sub>CBO</sub>	Collector-Base Voltage	60	V	
V <sub>EBO</sub>	Emitter-Base Voltage	6	V	
I <sub>C</sub>	Collector Current - Continuous	100	mA	
T <sub>J,</sub> T <sub>STG</sub>	Storage Junction Temperature Range	- 55 ~ 150	°C	

## Electrical Characteristics ${\rm T_{C}=25^{\circ}C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Chara	cteristics					
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 2{\rm mA}, I_{\rm B} = 0$	50			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 10\mu {\rm A}, I_{\rm E} = 0$	60			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10\mu A, I_{\rm C} = 0$	6			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 50V, V_{BE} = 0$			15	nA
I <sub>EBO</sub>	Emitter-Base Leakage Current	$V_{EB} = 4V, I_{E} = 0$			15	nA
On Chara	cteristics					
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 10\mu A$	40			
		$V_{CE} = 5V, I_{C} = 100mA$	80			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0.5mA			0.25	V
		I <sub>C</sub> = 100mA, I <sub>B</sub> = 5mA			0.6	
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 100mA, I <sub>B</sub> = 5mA			1.2	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = 5V, I_C = 2mA$	0.55		0.7	V
Dynamic (	Characteristics					
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 10mA, f = 100MHz$	150			MHz
C <sub>ob</sub>	Output Capacitance	$V_{CE} = 10V, I_{C} = 0, f = 1MHz$			5	pF
h <sub>fe</sub>	Small Signal Current Gain	V <sub>CE</sub> = 5V, I <sub>C</sub> = 2mA, f = 1KHz	240		500	
NF	Noise Figure	$V_{CE} = 5V, I_{C} = 0.2mA$	1		10	dB
		$R_{S} = 2K\Omega$ , f = 1KHz, BW = 200Hz				

Thermal Characteristics T <sub>A</sub> =25°C unless otherwise noted				
Symbol	Parameter	Max.	Units	
P <sub>D</sub>	Total Device Dissipation @T <sub>A</sub> =25°C	350	mW	
	Derate above 25°C	2.8	mW/°C	
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	357	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W	

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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